

## **isc** Silicon NPN Darlington Power Transistor

# **BD683**

### DESCRIPTION

- Collector-Emitter Breakdown Voltage-: V<sub>(BR)CEO</sub> = 120V(Min.)
- DC Current Gain-: h<sub>FE</sub> = 750(Min)@ I<sub>C</sub>= 1.5A
- Complement to Type BD684
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

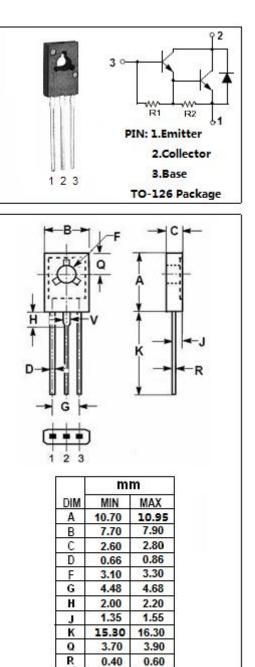
#### **APPLICATIONS**

· Designed for use as output devices in complementary general-purpose amplifier applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)							
SYMBOL	PARAMETER	VALUE	UNIT				
V <sub>CBO</sub>	Collector-Base Voltage	140	V				
V <sub>CEO</sub>	Collector-Emitter Voltage	120	V				
$V_{\text{EBO}}$	Emitter-Base Voltage	5	V A				
Ιc	Collector Current-Continuous	4					
I <sub>B</sub>	Base Current	0.1	A				
Pc	Collector Power Dissipation $T_c$ =25 °C	40	W				
Ti	Junction Temperature	150	°C				
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C				

#### **THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	МАХ	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case		°C/W



v

1.17

1.37



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## **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 50mA; I <sub>B</sub> = 0	120		V
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 1.5A; I <sub>B</sub> = 6mA		2.5	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	Ic= 1.5A; Vce= 3V		2.5	V
I <sub>CEO</sub>	Collector Cutoff Current	V <sub>CE</sub> = 120V; I <sub>B</sub> = 0		0.5	mA
І <sub>сво</sub>	Collector Cutoff Current	V <sub>CB</sub> = 140V; I <sub>E</sub> = 0 V <sub>CB</sub> = 70V; I <sub>E</sub> = 0;T <sub>C</sub> = 150℃		0.2 1.0	mA
Іево	Emitter Cutoff Current	V <sub>EB</sub> = 5V; Ic= 0		2.0	mA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 1.5 A ; V <sub>CE</sub> = 3V	750		
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 0.5 A ; V <sub>CE</sub> = 3V		2200	
h <sub>FE-3</sub>	DC Current Gain	I <sub>C</sub> = 4 A ; V <sub>CE</sub> = 3V		1500	

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